NSN 5961-00-904-2019

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-904-2019 **Inclosure Material:** Metal **Overall Length:** Between 0.260 inches and 0.300 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.450 inches **End Application:** Engine, aircraft, f100-pw-200 (f-16a/b/c/d); los angeles class ssn (688); missile, air-to-air, sparrow (aim-7); deep submergence systems programs (dssp); missile, all-weather antiship, harpoon (agm-84); helicopter, advance attack, ah-1w; virginia class cgn (41); sturgeon class ssn (637); missile, air-to-air, phoenix (aim-84) **Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method: Terminal Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 repetitive peak reverse voltage, peak total value and 200.0 nonrepetitive peak reverse voltage, peak total value **Current Rating Per Characteristic:** 2.00 milliamperes forward current, average peak **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** Weapon system essential **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 80131-release5039 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**